

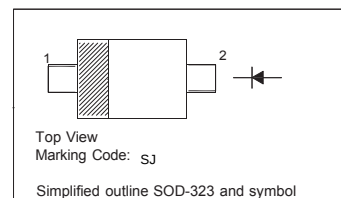
1A Surface Mount Schottky Barrier Diode

Features

For use in low voltage, high frequency inverters
Free wheeling, and polarity protection applications.

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

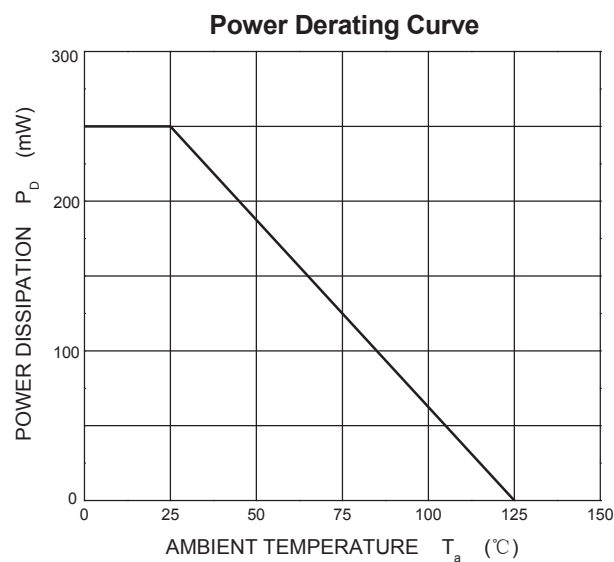
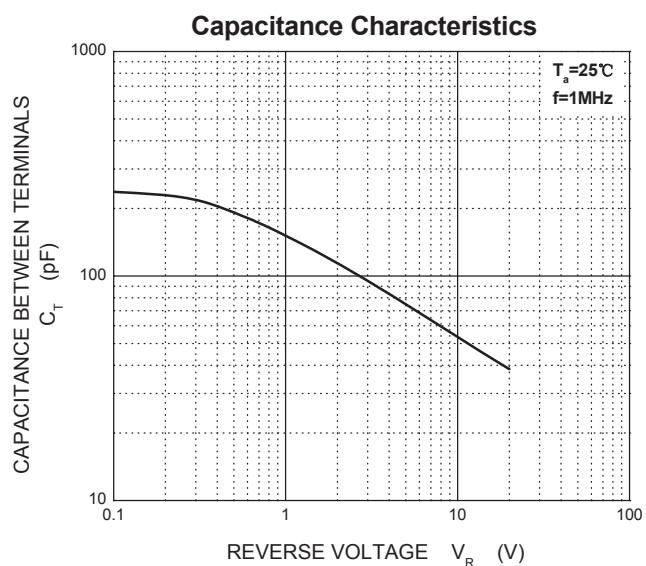
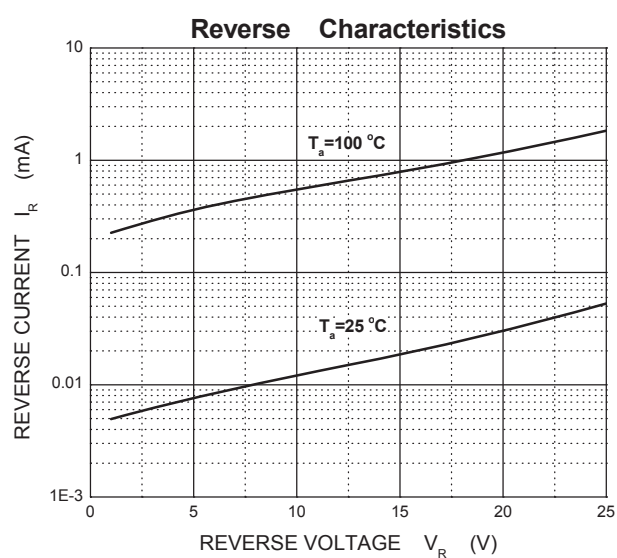
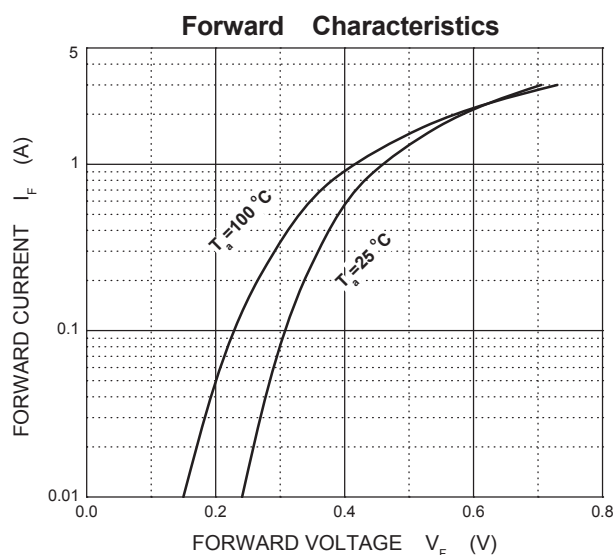
Parameter	Symbol	Value	Unit
Reverse Voltage	V_R	20.0	V
Average Forward Rectified Current	$I_{F(AV)}$	1.0	A
Non-Repetitive Peak Forward Surge Current (8.3 ms Single Half Sine-Wave)	I_{FSM}	25	A
Power Dissipation	P_{tot}	250	mW
Operating Temperature Range	T_j	125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	- 55 to + 125	$^\circ\text{C}$

Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at $I_R = 1\text{ mA}$	$V_{(BR)R}$	20.0	-	V
Reverse Current at $V_R = 20.0\text{V}$	I_R	-	1	mA
Forward Voltage at $I_F = 1\text{ A}$ at $I_F = 3\text{ A}$	V_F	- -	0.45 0.75	V
Total Capacitance at $V_R = 4\text{ V}$, $f = 1\text{ MHz}$	C_{tot}	-	120	pF

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Typical Characteristics

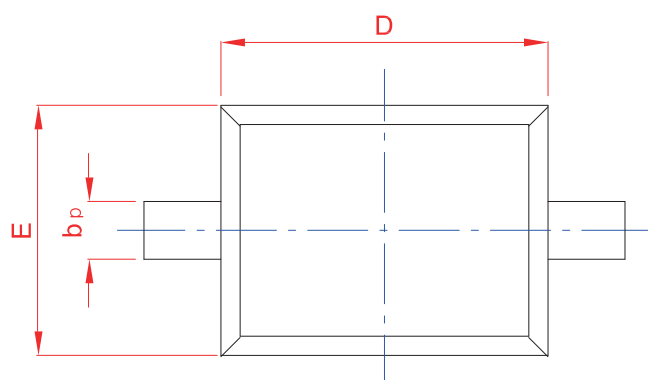
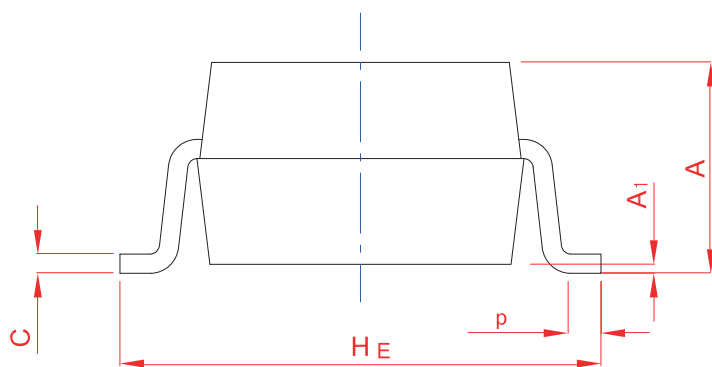
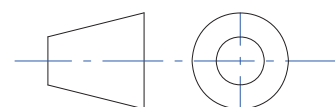


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PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-323



UNIT	A	b _p	C	D	E	H _E	A ₁	L _p
mm	1.20 0.90	0.40 0.25	0.15 0.10	1.80 1.60	1.35 1.15	2.80 2.30	0.10 0.01	0.50 0.20